74LV595

8-bit serial-in/serial-out or parallel-out shift register; 3-state
Rev. 6 — 8 April 2024 Product data sheet

1. General description

The 74LV595 is an 8-bit serial-in/serial or parallel-out shift register with a storage register and 3-state outputs. Both the shift and storage register have separate clocks. The device features a serial input (DS) and a serial output (Q7S) to enable cascading and an asynchronous reset $\overline{\text{MR}}$ input. A LOW on $\overline{\text{MR}}$ will reset the shift register. Data is shifted on the LOW-to-HIGH transitions of the SHCP input. The data in the shift register is transferred to the storage register on a LOW-to-HIGH transition of the STCP input. If both clocks are connected together, the shift register will always be one clock pulse ahead of the storage register. Data in the storage register appears at the output whenever the output enable input ($\overline{\text{OE}}$) is LOW. A HIGH on $\overline{\text{OE}}$ causes the outputs to assume a high-impedance OFF-state. Operation of the $\overline{\text{OE}}$ input does not affect the state of the registers. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess V_{CC}.

2. Features and benefits

- Wide supply voltage range from 1.0 V to 3.6 V
- · CMOS low power dissipation
- · Direct interface with TTL levels
- Typical output ground bounce < 0.8 V at V_{CC} = 3.3 V and T_{amb} = 25 °C
- Typical HIGH-level output voltage (V_{OH}) undershoot: > 2 V at V_{CC} = 3.3 V and T_{amb} = 25 °C
- Has a shift register with direct clear
- · Output capability:
 - Parallel outputs; bus driver
 - Serial output; standard
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
- · ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- · Multiple package options
- Specified from -40 °C to 85 °C and -40 °C to 125 °C

3. Applications

- Serial-to-parallel data conversion
- Remote control holding register



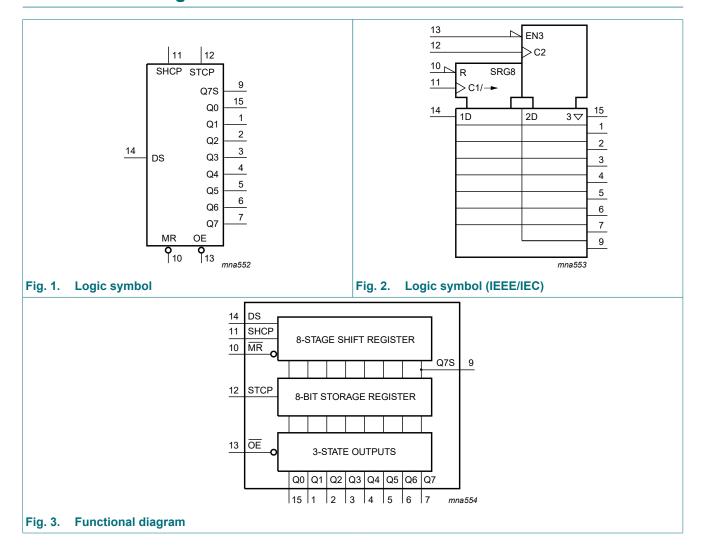
8-bit serial-in/serial-out or parallel-out shift register; 3-state

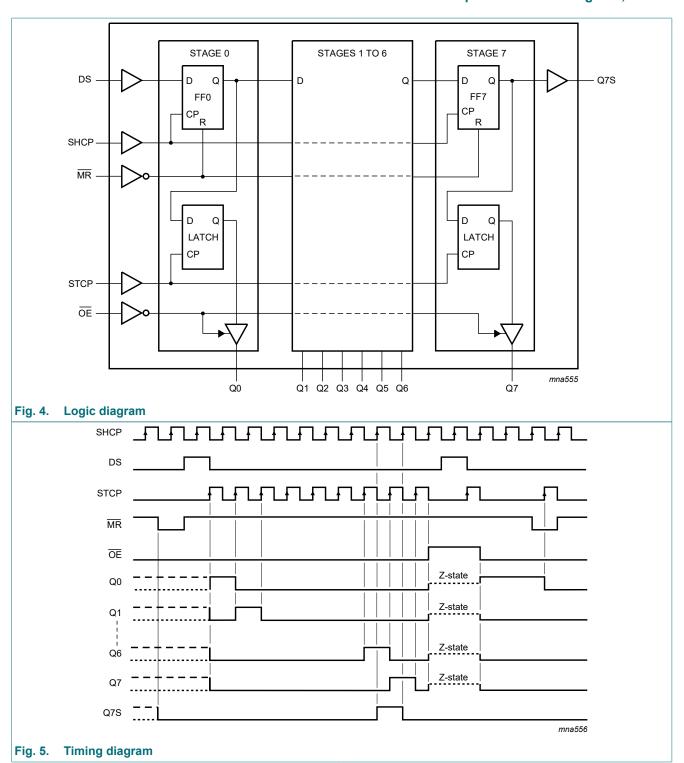
4. Ordering information

Table 1. Ordering information

Type number	Package							
	Temperature range	Name	Description	Version				
74LV595D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1				
74LV595PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1				

5. Functional diagram

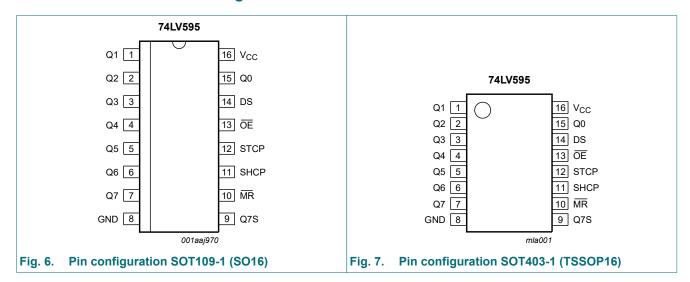




8-bit serial-in/serial-out or parallel-out shift register; 3-state

6. Pinning information

6.1. Pinning



6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7	15, 1, 2, 3, 4, 5, 6, 7	parallel data output
GND	8	ground (0 V)
Q7S	9	serial data output
MR	10	master reset (active LOW)
SHCP	11	shift register clock input
STCP	12	storage register clock input
ŌE	13	output enable input (active LOW)
DS	14	serial data input
V _{CC}	16	supply voltage

8-bit serial-in/serial-out or parallel-out shift register; 3-state

7. Functional description

Table 3. Function table

 $H = HIGH \ voltage \ state; \ L = LOW \ voltage \ state; \ \uparrow = LOW - to - HIGH \ transition;$

X = don't care; NC = no change; Z = high-impedance OFF-state.

Input					Outpu	t	Function
SHCP	STCP	OE	MR	DS	Q7S	Qn	
Χ	Х	L	L	Х	L	NC	a LOW-state on MR only affects the shift register
Χ	1	L	L	Χ	L	L	empty shift register loaded into storage register
Χ	Х	Н	L	Х	L	Z	shift register clear; parallel outputs in high-impedance OFF-state
↑	Х	L	Н	Н	Q6S	NC	logic HIGH-state shifted into shift register stage 0. Contents of all shift register stages shifted through, e.g. previous state of stage 6 (internal Q6S) appears on the serial output (Q7S).
X	1	L	Н	Х	NC	QnS	contents of shift register stages (internal QnS) are transferred to the storage register and parallel output stages
↑	1	L	Н	Х	Q6S	QnS	contents of shift register shifted through; previous contents of the shift register is transferred to the storage register and the parallel output stages

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{OK}	output clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±50	mA
Io	output current	-0.5 V < V _O < V _{CC} + 0.5 V	-		
		standard driver outputs		25	mA
		bus driver outputs		35	mA
I _{CC}	supply current	standard driver outputs		50	mA
		bus driver outputs		70	mA
I_{GND}	ground current	standard driver outputs	-50		mA
		bus driver outputs	-70		mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ [1]	-	500	mW

^[1] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.

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9. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		1.0	3.3	3.6	V
VI	input voltage		0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 1.0 V to 2.0 V	-	-	500	ns/V
		V _{CC} = 2.0 V to 2.7 V	-	-	200	ns/V
		V _{CC} = 2.7 V to 3.6 V	-	-	100	ns/V

10. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	+125 °C	Unit
			Min	Typ [1]	Max	Min	Max	
V _{IH}	HIGH-level input	V _{CC} = 1.2 V	0.9	-	-	0.9	-	V
	voltage	V _{CC} = 2.0 V	1.4	-	-	1.4	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
V _{IL}	LOW-level input	V _{CC} = 1.2 V		-	0.3	-	0.3	V
	voltage	V _{CC} = 2.0 V	-	-	0.6	-	0.6	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
V _{OH} HIGH-level output voltage	all outputs; $V_I = V_{IH}$ or V_{IL} ; $I_O = -100 \mu A$							
		V _{CC} = 1.2 V	-	1.2	-	-	-	V
		V _{CC} = 2.0 V	1.8	2.0	-	1.8	-	V
		V _{CC} = 2.7 V	2.5	2.7	-	2.5	-	V
		V _{CC} = 3.0 V	2.8	3.0	-	2.8	-	V
		standard outputs; V _I = V _{IH} or V _{IL} ; I _O = -6 mA; V _{CC} = 3.0 V	2.4	2.82	-	2.2	-	V
		bus outputs; $V_I = V_{IH}$ or V_{IL} ; $I_O = -8$ mA; $V_{CC} = 3.0$ V	2.4	2.82	-	2.2	-	V
V _{OL}	LOW-level output voltage	all outputs; $V_I = V_{IH}$ or V_{IL} ; $I_O = 100 \mu A$						
		V _{CC} = 1.2 V	-	0	-	-	-	V
		V _{CC} = 2.0 V	-	0	0.2	-	0.2	V
		V _{CC} = 2.7 V	-	0	0.2	-	0.2	V
		V _{CC} = 3.0 V	-	0	0.2	-	0.2	V
		standard driver outputs V _{CC} = 3.0 V; I _O = 6 mA	-	0.25	0.4	-	0.5	V
		bus driver outputs V_{CC} = 3.0 V; I_{O} = 8 mA	-	0.20	0.4	-	0.5	V
l _l	input leakage current	V _{CC} = 3.6 V; V _I = 5.5 V or GND	-	-	1.0	-	1.0	μΑ

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Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to	+125 °C	Unit
			Min	Typ [1]	Max	Min	Max	
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 3.6 \text{ V}$	-	-	5	-	10	μΑ
I _{CC}	supply current	$V_{CC} = 3.6 \text{ V}; V_{I} = V_{CC} \text{ or GND};$ $I_{O} = 0 \text{ A}$	-	-	20	-	160	μΑ
ΔI _{CC}	additional supply current	per input pin; $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V};$ $V_I = V_{CC} - 0.6 \text{ V}$	-	-	500	-	850	μΑ
Cı	input capacitance		-	3.5	-	-	-	pF

^[1] All typical values are measured at V_{CC} = 3.3 V (unless stated otherwise) and T_{amb} = 25 °C.

11. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Fig. 13.

Symbol	Parameter	Conditions		-40	°C to +85	5 °C	-40 °C to	+125 °C	Unit
				Min	Typ [1]	Max	Min	Max	
t _{pd}	propagation delay	SHCP to Q7S; see Fig. 8	[2]						
		V _{CC} = 1.2 V		-	95	-	-	-	ns
		V _{CC} = 2.0 V		-	32	61	-	75	ns
		V _{CC} = 2.7 V		-	24	45	-	55	ns
		V _{CC} = 3.3 V; C _L = 15 pF		-	15	-	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	18	36	-	44	ns
		STCP to Qn; see Fig. 9	[2]						
		V _{CC} = 1.2 V		-	100	-	-	-	ns
		V _{CC} = 2.0 V		-	34	65	-	77	ns
		V _{CC} = 2.7 V		-	25	48	-	56	ns
		V _{CC} = 3.3 V; C _L = 15 pF		-	16	-	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	19	38	-	45	ns
		MR to Q7S; see Fig. 11							
		V _{CC} = 1.2 V		-	85	-	-	-	ns
		V _{CC} = 2.0 V		-	29	56	-	66	ns
		V _{CC} = 2.7 V		-	21	41	-	49	ns
		V _{CC} = 3.3 V; C _L = 15 pF		-	14	-	-	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	16	33	-	33	ns
t _{en}	enable time	OE to Qn; see Fig. 12	[4]						
		V _{CC} = 1.2 V		-	85	-	-	-	ns
		V _{CC} = 2.0 V		-	29	56	-	66	ns
		V _{CC} = 2.7 V		-	21	41	-	49	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	16	33	-	39	ns
t _{dis}	disable time	OE to Qn; see Fig. 12	[5]						
		V _{CC} = 1.2 V		-	65	-	-	-	ns
		V _{CC} = 2.0 V		-	24	40	-	49	ns
		V _{CC} = 2.7 V		-	18	32	-	37	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	14	26	-	30	ns

Symbol	Parameter	Conditions		-40	°C to +85	5 °C	-40 °C to	+125 °C	Unit
				Min	Typ [1]	Max	Min	Max	
t _W	pulse width	SHCP, HIGH or LOW; see Fig. 8							
		V _{CC} = 2.0 V		34	10	-	41	-	ns
		V _{CC} = 2.7 V		25	8	-	30	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	20	6	-	24	-	ns
		STCP, HIGH or LOW; see Fig. 9							
		V _{CC} = 2.0 V		34	7	-	41	-	ns
		V _{CC} = 2.7 V		25	5	-	30	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	20	4	-	24	-	ns
		MR LOW; see Fig. 11							
		V _{CC} = 2.0 V		34	10	-	41	-	ns
		V _{CC} = 2.7 V		25	8	-	30	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	20	6	-	24	-	ns
t _{su}	set-up time	DS to SHCP; see Fig. 10							
		V _{CC} = 1.2 V		-	40	-	-	-	ns
		V _{CC} = 2.0 V		26	14	-	31	-	ns
		V _{CC} = 2.7 V		19	10	-	23	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	15	8	-	18	-	ns
		SHCP to STCP; see Fig. 9							
		V _{CC} = 1.2 V		-	40	-	-	-	ns
		V _{CC} = 2.0 V		26	14	-	31	-	ns
		V _{CC} = 2.7 V		19	10	-	23	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	15	8	-	18	-	ns
t _h	hold time	DS to SHCP; see Fig. 10							
		V _{CC} = 1.2 V		-	-10.0	-	-	-	ns
		V _{CC} = 2.0 V		5.0	-4.0	-	5.0	-	ns
		V _{CC} = 2.7 V		5.0	-3.0	-	5.0	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	5.0	-2.0	-	5.0	-	ns
t _{rec}	recovery time	MR to SHCP; see Fig. 11							
		V _{CC} = 1.2 V		-	-35	-	-	-	ns
		V _{CC} = 2.0 V		5.0	-12.0	-	5.0	-	ns
		V _{CC} = 2.7 V		5.0	-9.0	-	5.0	-	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	5.0	-7.0	-	5.0	-	ns
f _{max}	maximum frequency	SHCP or STCP; see Fig. 8 and Fig. 9							
		V _{CC} = 2.0 V		14.0	40.0	-	12	-	MHz
		V _{CC} = 2.7 V		19.0	58.0	-	16	-	MHz
		V _{CC} = 3.3 V; C _L = 15 pF		-	77	-	-	-	MHz
		V _{CC} = 3.0 V to 3.6 V	[3]	24.0	70.0	-	20	-	MHz

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Symbol	Parameter	Conditions -40 °C 1		°C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	
C _{PD}	power dissipation capacitance	$V_1 = GND \text{ to } V_{CC}; V_{CC} = 3.0 \text{ V}$ [6]	-	115	-	-	-	pF

- [1] Typical values are measured at T_{amb} = 25 °C.
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [3] Typical value measured at V_{CC} = 3.3 V.
- [4] t_{en} is the same as t_{PZH} and t_{PZL} .
- [5] t_{dis} is the same as t_{PHZ} and t_{PLZ} .
- [6] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

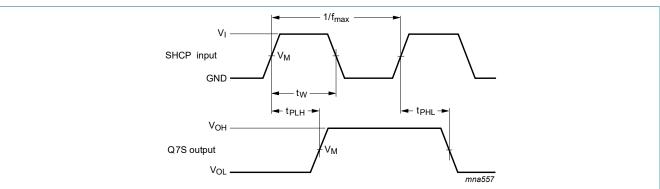
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$

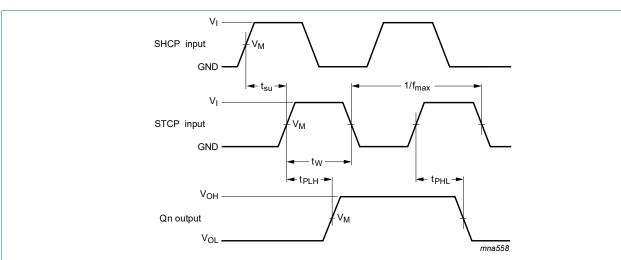
11.1. Waveforms and test circuit



Measurement points are given in Table 8.

 V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

Fig. 8. The shift clock (SHCP) to serial data output (Q7S) propagation delays, the shift clock pulse width and maximum shift clock frequency



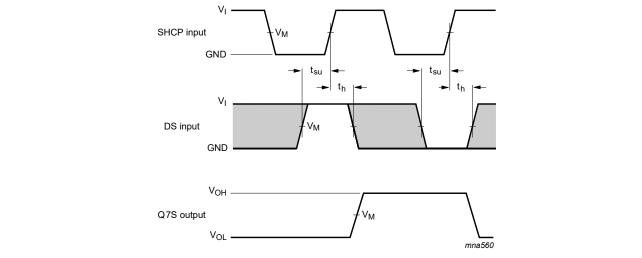
Measurement points are given in Table 8.

 V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

Fig. 9. The storage clock (STCP) to parallel data output (Qn) propagation delays, the storage clock pulse width and the shift clock to storage clock set-up time

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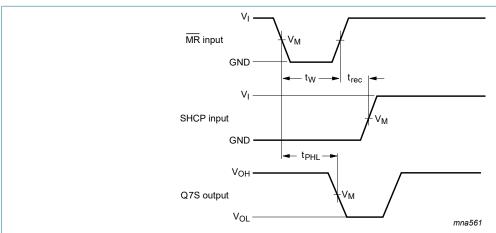


Measurement points are given in Table 8.

The shaded areas indicate when the input is permitted to change for predictable output performance.

V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

Fig. 10. The data set-up and hold times for the serial data input (DS)



Measurement points are given in Table 8.

 V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

Fig. 11. The master reset (MR) pulse width, the master reset to serial data output (Q7S) propagation delays and the master reset to shift clock (SHCP) recovery time

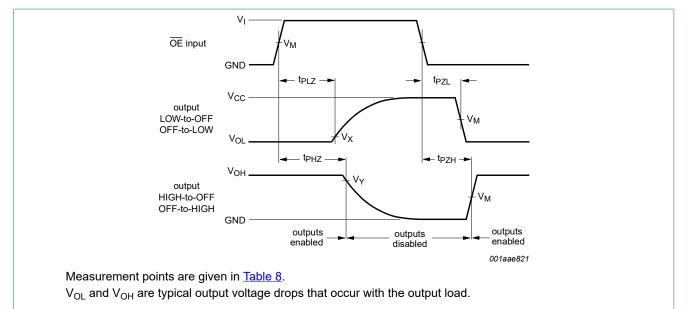
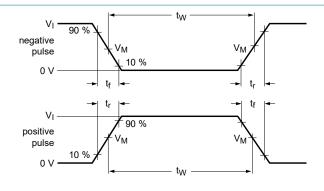


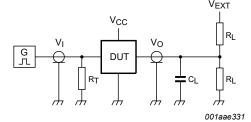
Fig. 12. Enable and disable times

Table 8. Measurement points

Supply voltage	Input	Output	Output					
V _{CC}	V _M	V _M	V _X	V _Y				
V _{CC} < 2.7 V	0.5V _{CC}	0.5V _{CC}	V _{OL} + 0.1V _{CC}	V _{OH} - 0.1V _{CC}				
V _{CC} ≥ 2.7 V	1.5 V	1.5 V	V _{OL} + 0.3 V	V _{OH} - 0.3 V				

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Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig. 13. Test circuit for measuring switching times

Table 9. Test data

Supply voltage	Input Lo		Load		V _{EXT}			
V _{CC}	VI	t _r , t _f	CL	R_L	t _{PLH} , t _{PHL}	t _{PLZ} , t _{PZL}	t _{PHZ} , t _{PZH}	
< 2.7 V	V _{CC}	≤ 2.5 ns	50 pF	1 kΩ	open	2V _{CC}	GND	
2.7 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	1 kΩ	open	2V _{CC}	GND	

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12. Package outline

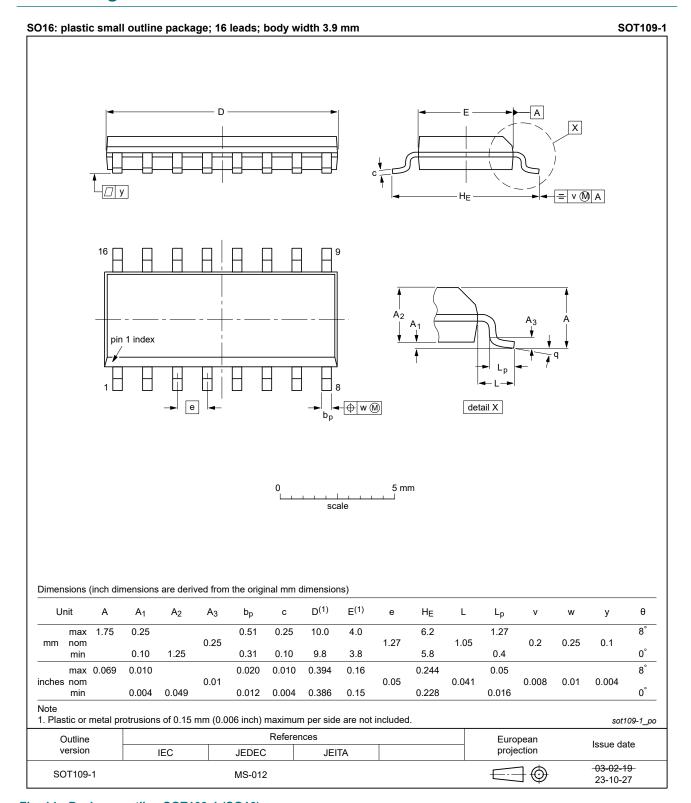


Fig. 14. Package outline SOT109-1 (SO16)

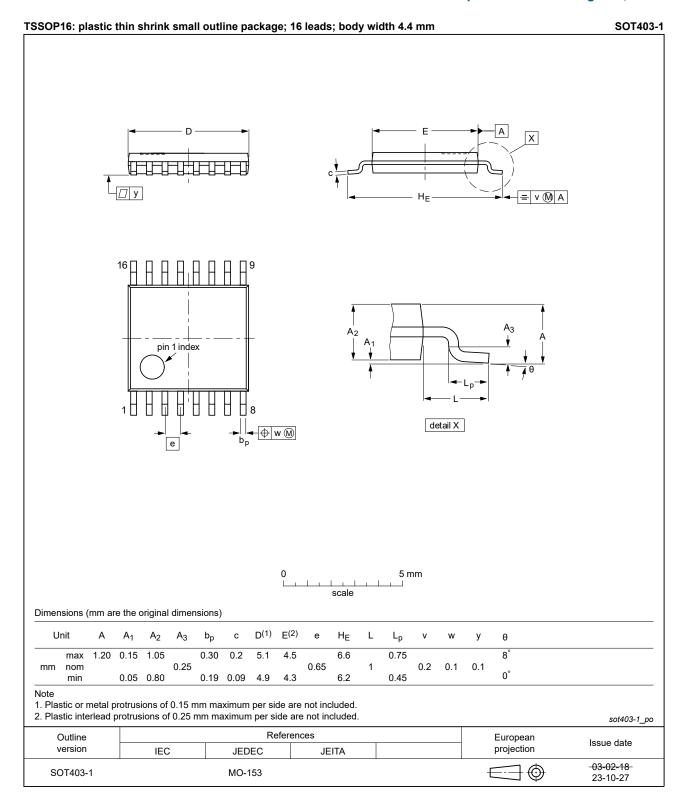


Fig. 15. Package outline SOT403-1 (TSSOP16)

8-bit serial-in/serial-out or parallel-out shift register; 3-state

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74LV595 v.6	20240408	Product data sheet	-	74LV595 v.5		
Modifications:	and MO-15	 Fig. 14, Fig. 15: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and MO-153. Section 2: ESD specification updated according to the latest JEDEC standard. 				
74LV595 v.5	20210929	Product data sheet	-	74LV595 v.4		
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. 					
	Type numberSection 1 a	er 74LV595DB (SOT338-2 nd <u>Section 2</u> updated.	ve been adapted to the new company name where appropriate. 74LV595DB (SOT338-1/SSOP16) removed. Section 2 updated. ating values for P _{tot} total power dissipation updated.			
74LV595 v.4	20160318	Product data sheet	-	74LV595 v.3		
Modifications:	Type number 74LV595N (SOT38-4) removed.					
74LV595 v.3	20090421	Product data sheet	-	74LV595 v.2		
Modifications:	guidelines o	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. 				
74LV595 v.2	980402	Product data sheet	-	74LV595 v.1		
74LV595 v.1	970606	Product data sheet	-	-		

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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8-bit serial-in/serial-out or parallel-out shift register; 3-state

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